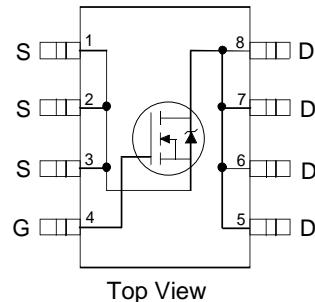


Features

- $V_{DS} (V) = 40V$
- $R_{DS(on)} < 17m\Omega$ ($V_{GS} = 10V$)
- $R_{DS(on)} < 21m\Omega$ ($V_{GS} = 4.5V$)

Applications

- High Frequency Isolated DC-DC Converters with Synchronous Rectification for Telecom and Industrial Use
- High Frequency Buck Converters for Computer Processor Power
- Lead-Free



Benefits

- Ultra-Low Gate Impedance
- Very Low $R_{DS(on)}$
- Fully Characterized Avalanche Voltage and Current

Absolute Maximum Ratings

Symbol	Parameter	Max.	Units
V_{DS}	Drain-Source Voltage	40	V
V_{GS}	Gate-to-Source Voltage	± 20	V
$I_D @ T_A = 25^\circ C$	Continuous Drain Current, $V_{GS} @ 10V$	9.0	A
$I_D @ T_A = 70^\circ C$	Continuous Drain Current, $V_{GS} @ 10V$	7.3	
I_{DM}	Pulsed Drain Current①	73	
$P_D @ T_A = 25^\circ C$	Maximum Power Dissipation③	2.5	W
$P_D @ T_A = 70^\circ C$	Maximum Power Dissipation③	1.6	W
	Linear Derating Factor	0.02	mW/°C
T_J, T_{STG}	Junction and Storage Temperature Range	-55 to + 150	°C

Thermal Resistance

Symbol	Parameter	Typ.	Max.	Units
$R_{\theta JL}$	Junction-to-Drain Lead		20	
$R_{\theta JA}$	Junction-to-Ambient ④		50	°C/W

Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Starting $T_J = 25^\circ C$, $L = 8.1mH$
 $R_G = 25\Omega$, $I_{AS} = 7.2A$.
- ③ Pulse width $\leq 400\mu s$; duty cycle $\leq 2\%$.
- ④ When mounted on 1 inch square copper board.

Static @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Conditions
$V_{(\text{BR})\text{DSS}}$	Drain-to-Source Breakdown Voltage	40			V	$V_{GS} = 0V, I_D = 250\mu\text{A}$
$\Delta V_{(\text{BR})\text{DSS}}/\Delta T_J$	Breakdown Voltage Temp. Coefficient		0.04		V/ $^\circ\text{C}$	Reference to $25^\circ\text{C}, I_D = 1\text{mA}$
$R_{DS(\text{on})}$	Static Drain-to-Source On-Resistance	12	17		$\text{m}\Omega$	$V_{GS} = 10V, I_D = 9.0\text{A}$ ③
			15.5	21		$V_{GS} = 4.5V, I_D = 7.2\text{A}$ ③
$V_{GS(\text{th})}$	Gate Threshold Voltage	1.0		3.0	V	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$
I_{DSS}	Drain-to-Source Leakage Current		20		μA	$V_{DS} = 32V, V_{GS} = 0V$
			100			$V_{DS} = 32V, V_{GS} = 0V, T_J = 125^\circ\text{C}$
I_{GSS}	Gate-to-Source Forward Leakage			200	nA	$V_{GS} = 16V$
	Gate-to-Source Reverse Leakage			-200		$V_{GS} = -16V$

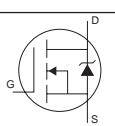
Dynamic @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Units	Conditions
g_{fs}	Forward Transconductance	17			S	$V_{DS} = 20V, I_D = 7.2\text{A}$
Q_g	Total Gate Charge		15	23	nC	$I_D = 7.2\text{A}$
Q_{gs}	Gate-to-Source Charge		7.0	11		$V_{DS} = 20V$
Q_{gd}	Gate-to-Drain ("Miller") Charge		5.0	8.0		$V_{GS} = 4.5V$ ③
Q_{oss}	Output Gate Charge		16	24		$V_{GS} = 0V, V_{DS} = 16V$
$t_{d(on)}$	Turn-On Delay Time		11		ns	$V_{DD} = 20V$
t_r	Rise Time		2.2			$I_D = 7.2\text{A}$
$t_{d(off)}$	Turn-Off Delay Time		14			$R_G = 1.8\Omega$
t_f	Fall Time		3.5			$V_{GS} = 4.5V$ ③
C_{iss}	Input Capacitance		2000		pF	$V_{GS} = 0V$
C_{oss}	Output Capacitance		480			$V_{DS} = 20V$
C_{rss}	Reverse Transfer Capacitance		28			$f = 1.0\text{MHz}$

Avalanche Characteristics

Symbol	Parameter	Typ.	Max.	Units
E_{AS}	Single Pulse Avalanche Energy ②		210	mJ
I_{AR}	Avalanche Current ①		7.2	A

Diode Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Units	Conditions
I_s	Continuous Source Current (Body Diode)			2.3	A	MOSFET symbol showing the integral reverse p-n junction diode.
	Pulsed Source Current (Body Diode) ①			73		
V_{SD}	Diode Forward Voltage	0.80	1.3		V	$T_J = 25^\circ\text{C}, I_S = 7.2\text{A}, V_{GS} = 0V$ ③
			0.65			$T_J = 125^\circ\text{C}, I_S = 7.2\text{A}, V_{GS} = 0V$ ③
t_{rr}	Reverse Recovery Time	47	71	ns	nC	$T_J = 25^\circ\text{C}, I_F = 7.2\text{A}, V_R = 15V$ $dI/dt = 100\text{A}/\mu\text{s}$ ③
Q_{rr}	Reverse Recovery Charge	91	140			$T_J = 125^\circ\text{C}, I_F = 7.2\text{A}, V_R = 20V$ $dI/dt = 100\text{A}/\mu\text{s}$ ③
t_{rr}	Reverse Recovery Time	77	120	ns	nC	
Q_{rr}	Reverse Recovery Charge	150	230			

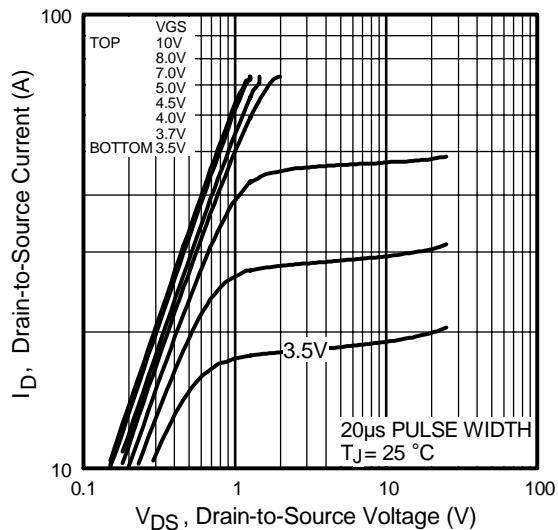


Fig 1. Typical Output Characteristics

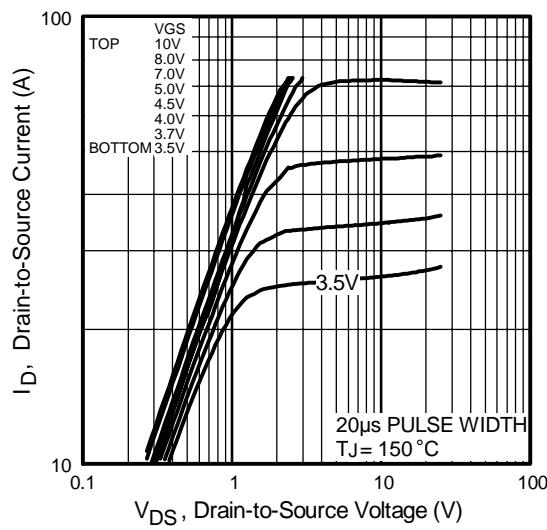


Fig 2. Typical Output Characteristics

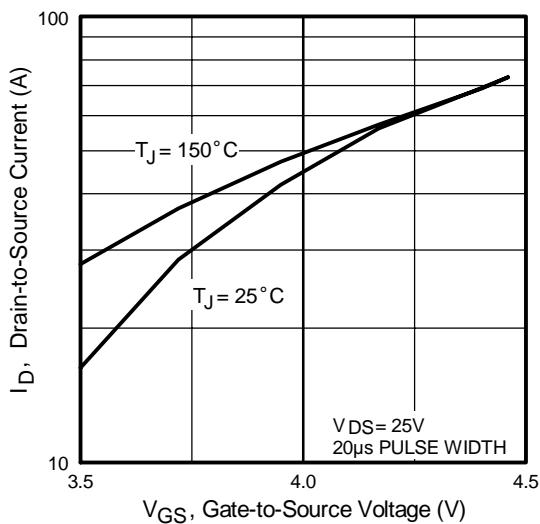


Fig 3. Typical Transfer Characteristics

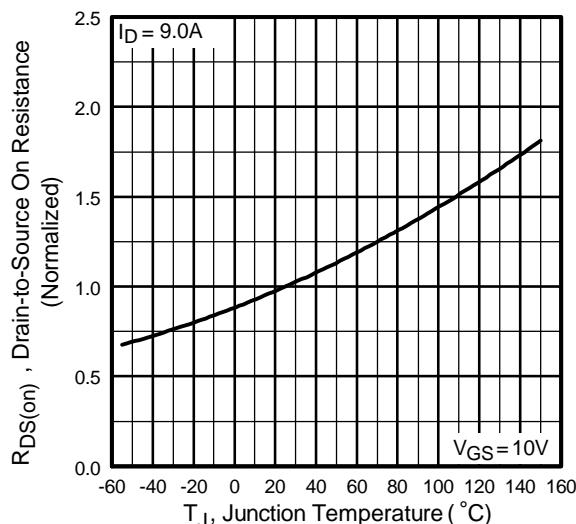


Fig 4. Normalized On-Resistance Vs. Temperature

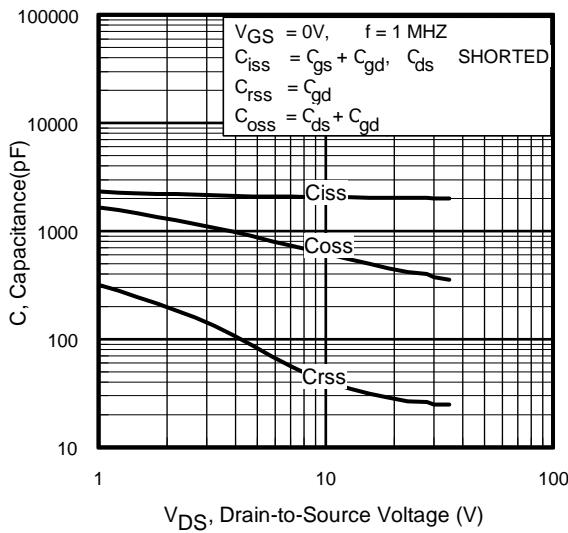


Fig 5. Typical Capacitance Vs.
Drain-to-Source Voltage

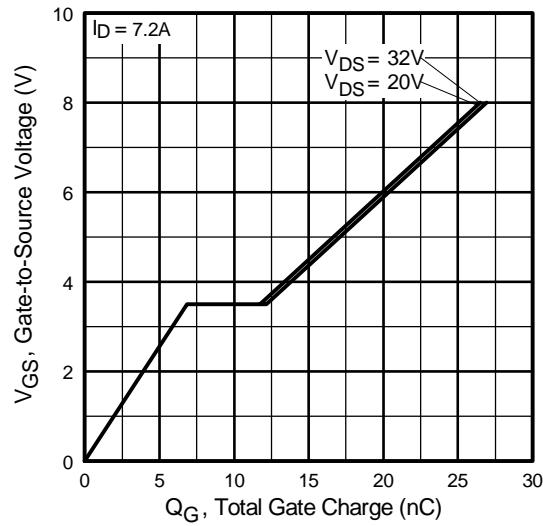


Fig 6. Typical Gate Charge Vs.
Gate-to-Source Voltage

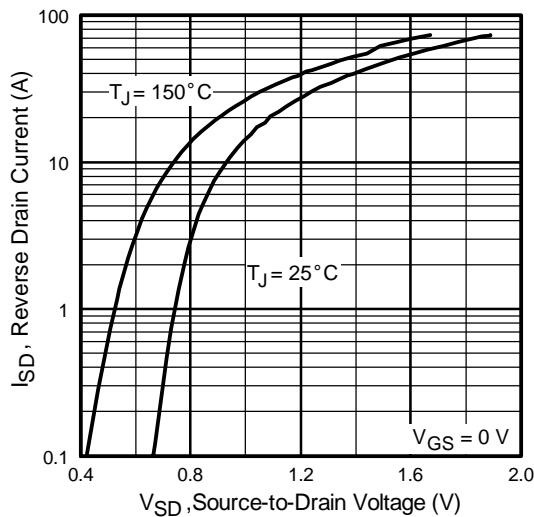


Fig 7. Typical Source-Drain Diode
Forward Voltage

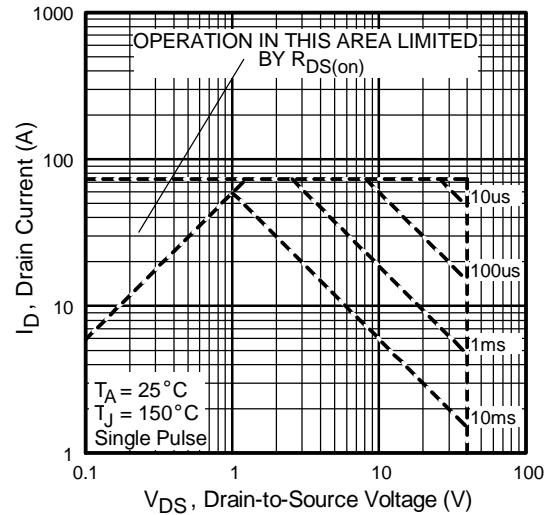


Fig 8. Maximum Safe Operating Area

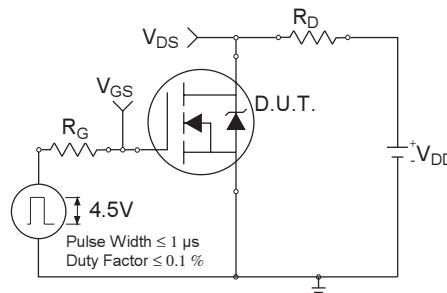
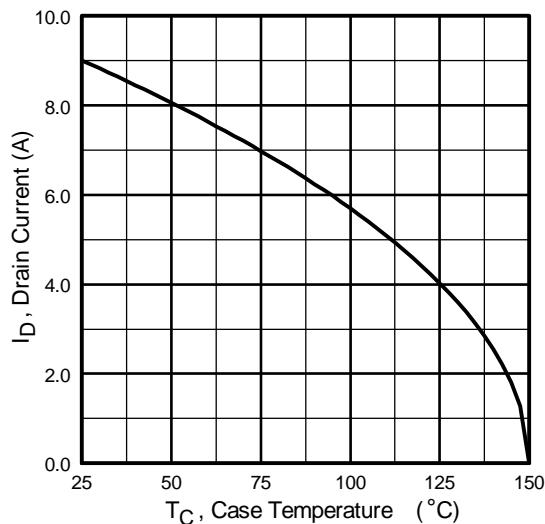


Fig 10a. Switching Time Test Circuit

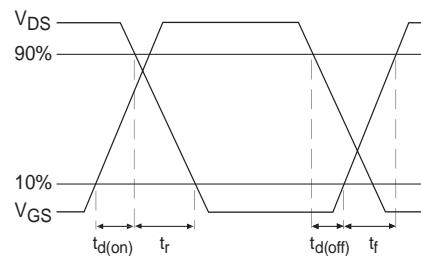


Fig 10b. Switching Time Waveforms

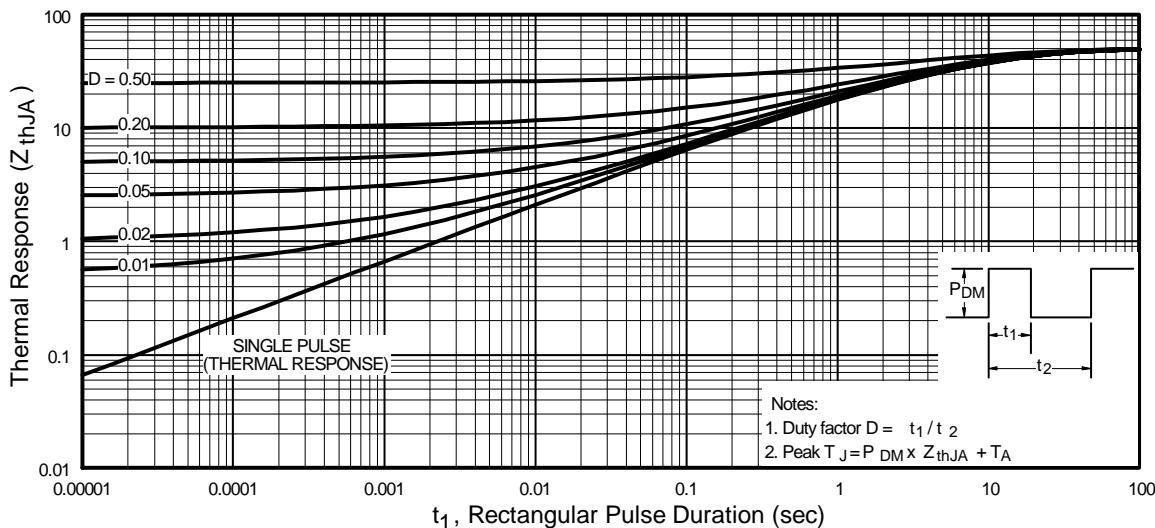


Fig 10. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

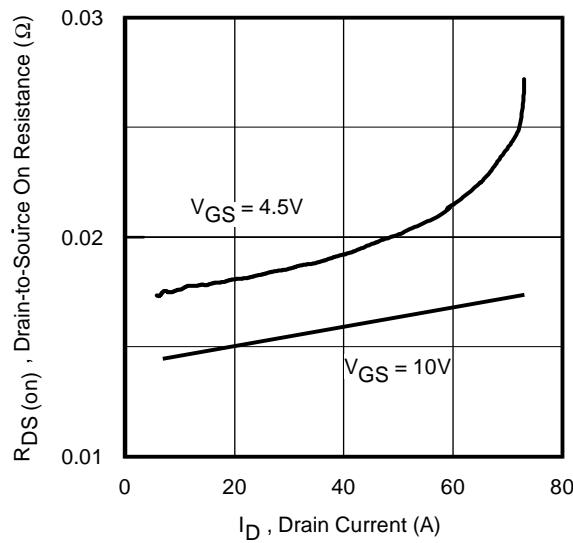


Fig 12. On-Resistance Vs. Drain Current

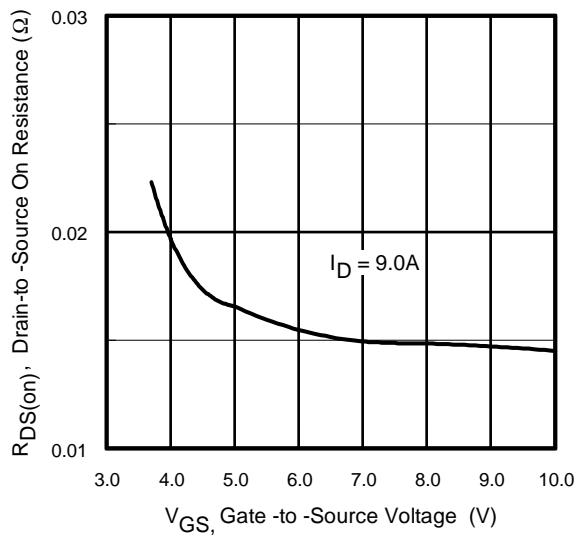


Fig 13. On-Resistance Vs. Gate Voltage

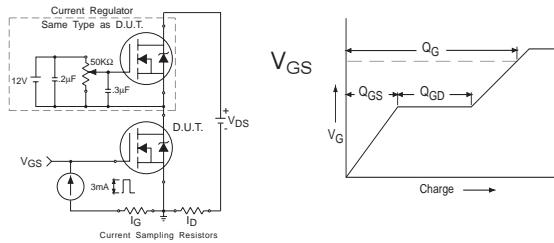


Fig 13a&b. Basic Gate Charge Test Circuit and Waveform

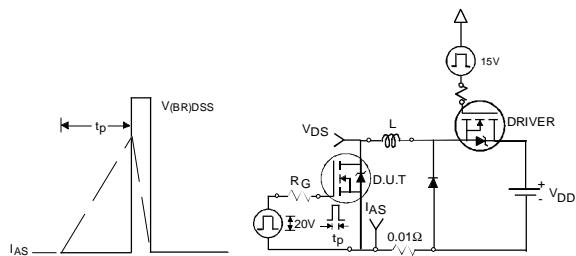


Fig 14a&b. Unclamped Inductive Test circuit and Waveforms

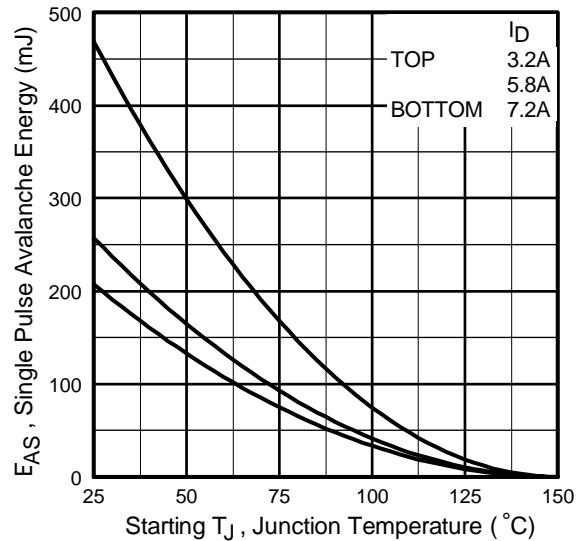
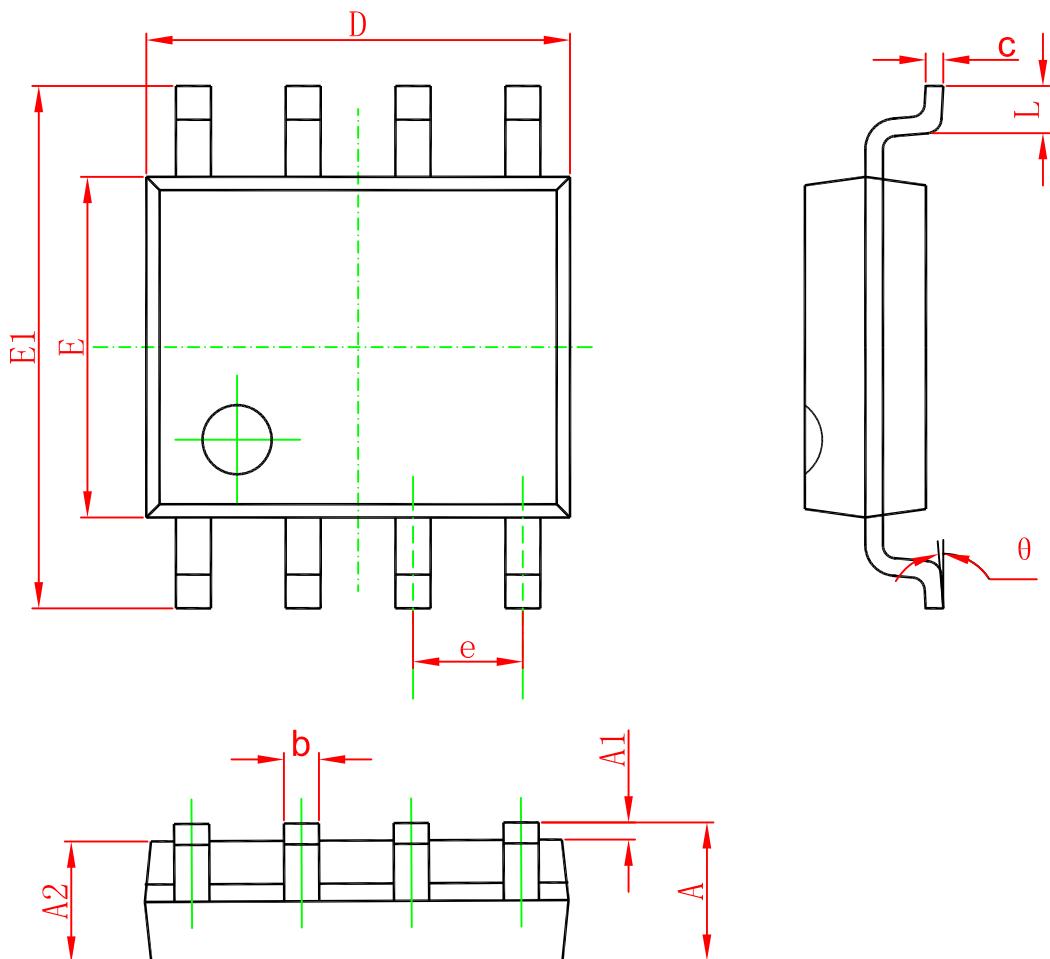


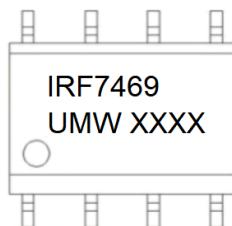
Fig 14c. Maximum Avalanche Energy Vs. Drain Current

SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

Marking



Ordering information

Order code	Package	Baseqty	Deliverymode
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[MCQ7328-TP](#) [SSM3J143TU,LXHF](#) [DMN12M3UCA6-7](#) [PJMF280N65E1_T0_00201](#) [PJMF380N65E1_T0_00201](#)
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